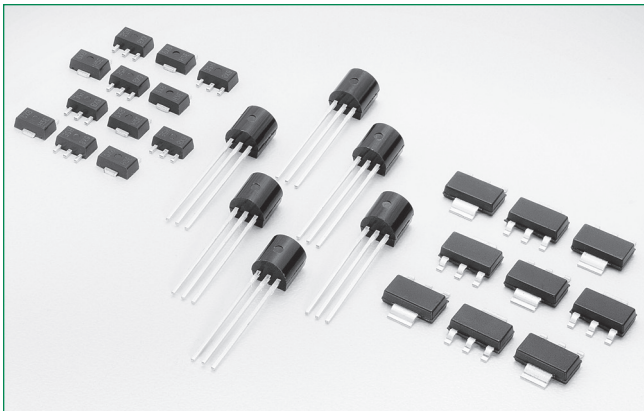


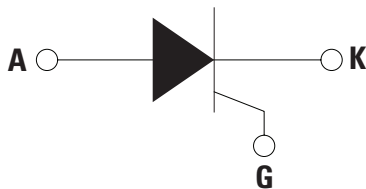
### SxX8xSx EV Series



#### Main Features

| Symbol            | Value            | Unit    |
|-------------------|------------------|---------|
| $I_{T(RMS)}$      | 0.8              | A       |
| $V_{DRM}/V_{RRM}$ | 400, 600, or 800 | V       |
| $I_{GT}$          | 5 to 450         | $\mu$ A |

#### Schematic Symbol



#### Description

This new component series offers high static dv/dt and low turn off time ( $t_q$ ) sensitive SCR. It is specifically designed for GFCI (Ground Fault Circuit Interrupter) and Gas Ignition applications. All SCRs junctions are glass-passivated to ensure long term reliability and parametric stability.

#### Features

- RoHS compliant and Halogen-Free
- Through-hole and surface mount packages
- Surge current capability > 10Amps
- Blocking voltage ( $V_{DRM}/V_{RRM}$ ) capability - up to 800V
- High dv/dt noise immunity
- Improved turn-off time ( $t_q$ ) < 25  $\mu$ sec
- Sensitive gate for direct microprocessor interface

#### Applications

The SxX8xSx EV series is specifically designed for GFCI (Ground Fault Circuit Interrupter) and gas ignition applications.

#### Additional Information



Resources



Samples

#### Absolute Maximum Ratings

| Symbol       | Parameter   | Value                      | Unit                      |                   |                        |
|--------------|---|----------------------------|---------------------------|-------------------|------------------------|
| $I_{T(RMS)}$ | RMS on-state current (full sine wave)   | TO-92                      | $T_c = 55^\circ\text{C}$  | 0.8               | A                      |
|              |   | SOT-89                     | $T_c = 60^\circ\text{C}$  | 0.8               | A                      |
|              |   | SOT-223                    | $T_L = 60^\circ\text{C}$  | 0.8               | A                      |
| $I_{T(AV)}$  | Average on-state current  | TO-92                      | $T_c = 55^\circ\text{C}$  | 0.51              | A                      |
|              |   | SOT-89                     | $T_c = 60^\circ\text{C}$  | 0.51              | A                      |
|              |   | SOT-223                    | $T_L = 60^\circ\text{C}$  | 0.51              | A                      |
| $I_{TSM}$    | Non repetitive surge peak on-state current (Single cycle, $T_{j\text{ initial}} = 25^\circ\text{C}$ ) | TO-92                      | $F = 50\text{Hz}$         | 8                 | A                      |
|              |   | SOT-89<br>SOT-223          |                           | $F = 60\text{Hz}$ | 10                     |
| $I^2t$       | $I^2t$ Value for fusing   | $t_p = 10\text{ ms}$       | $F = 50\text{ Hz}$        | 0.32              | $\text{A}^2\text{s}$   |
|              |   | $t_p = 8.3\text{ ms}$      | $F = 60\text{ Hz}$        | 0.41              | $\text{A}^2\text{s}$   |
| di/dt        | Critical rate of rise of on-state current $I_g = 10\text{mA}$   | TO-92<br>SOT-89<br>SOT-223 | $T_j = 125^\circ\text{C}$ | 50                | $\text{A}/\mu\text{s}$ |
| $I_{GM}$     | Peak Gate Current   | $t_p = 10\ \mu\text{s}$    | $T_j = 125^\circ\text{C}$ | 1.0               | A                      |
| $P_{G(AV)}$  | Average gate power dissipation  | —                          | $T_j = 125^\circ\text{C}$ | 0.1               | W                      |
| $T_{stg}$    | Storage junction temperature range  | —                          | —                         | -40 to 150        | $^\circ\text{C}$       |
| $T_j$        | Operating junction temperature range  | —                          | —                         | -40 to 125        | $^\circ\text{C}$       |

### Electrical Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

| Symbol    | Description                                | Test Conditions   | Limit | Value   |         |        |         | Unit             |
|-----------|--|---|-------|---------|---------|--------|---------|------------------|
|           |  |   |       | SxX8yS1 | SxX8yS2 | SxX8yS | SxX8yS3 |                  |
| $I_{GT}$  | DC Gate Trigger Current                    | $V_D = 6V$<br>$R_L = 100 \Omega$  | MIN.  | 0.5     | 1       | 15     | 70      | $\mu\text{A}$    |
|           |  |   | MAX.  | 5       | 50      | 200    | 450     | $\mu\text{A}$    |
| $V_{GT}$  | DC Gate Trigger Voltage                    | $V_D = 6V$<br>$R_L = 100 \Omega$  | MAX.  | 0.8     |         |        |         | V                |
| $V_{GRM}$ | Peak Reverse Gate Voltage                  | $I_{RG} = 10\mu\text{A}$  | MIN.  | 5       |         |        |         | V                |
| $I_H$     | Holding Current                            | $R_{GK} = 1 \text{ k}\Omega$<br>Initial Current = 20mA  | MAX.  | 5       |         |        | 10      | mA               |
| (dv/dt)s  | Critical Rate-of-Rise of Off-State Voltage | $T_J = 125^\circ\text{C}$<br>$V_D = V_{DRM} / V_{RRM}$<br>Exp. Waveform<br>$R_{GK} = 1 \text{ k}\Omega$ | MIN.  | 75      |         |        | 200     | V/ $\mu\text{s}$ |
| $V_{GD}$  | Gate Non-Trigger Voltage                   | $V_D = V_{DRM}$<br>$R_{GK} = 1 \text{ k}\Omega$<br>$T_J = 125^\circ\text{C}$                            | MIN.  | 0.2     |         |        |         | V                |
| $t_q$     | Turn-Off Time                              | $T_J = 25^\circ\text{C} @ 600V$<br>$R_{GK} = 1 \text{ k}\Omega$   | MAX.  | 30      | 25      | 25     | 15      | $\mu\text{s}$    |
| $t_{gt}$  | Turn-On Time                               | $I_G = 10\text{mA}$<br>PW = 15 $\mu\text{sec}$<br>$I_T = 1.6\text{A(pk)}$                               | TYP.  | 2.0     | 2.0     | 2.0    | 4       | $\mu\text{s}$    |

Note: x = voltage/100, y = package

### Static Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise specified)

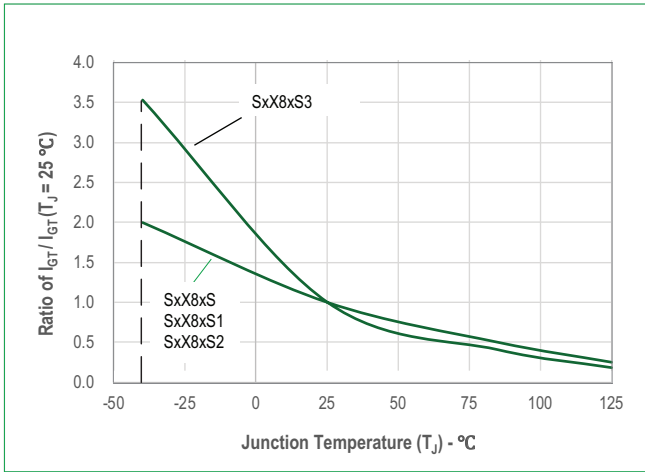
| Symbol    | Description                        | Test Conditions   | Limit | Value   |         |        |         | Unit          |
|-----------|------------------------------------|---|-------|---------|---------|--------|---------|---------------|
|           |                                    |   |       | SxX8yS1 | SxX8yS2 | SxX8yS | SxX8yS3 |               |
| $V_{TM}$  | Peak On-State Voltage              | $I_{TM} = 1.6\text{A (pk)}$   | MAX.  | 1.7     |         |        |         | V             |
| $I_{DRM}$ | Off-State Current, Peak Repetitive | $T_J = 25^\circ\text{C} @ V_D = V_{DRM}$<br>$R_{GK} = 1 \text{ k}\Omega$  | MAX.  | 3       |         |        |         | $\mu\text{A}$ |
|           |                                    | $T_J = 125^\circ\text{C} @ V_D = V_{DRM}$<br>$R_{GK} = 1 \text{ k}\Omega$ | MAX.  | 500     |         |        | 100     | $\mu\text{A}$ |

### Thermal Resistances

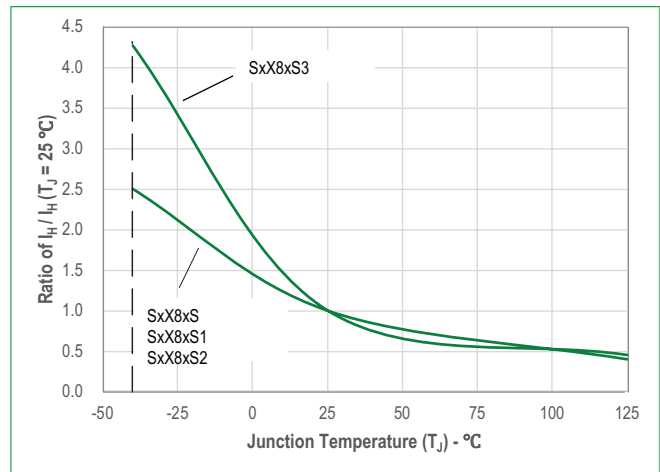
| Symbol          | Description           | Test Conditions               | Value   | Unit |                    |
|-----------------|-----------------------|-------------------------------|---------|------|--------------------|
| $R_{\theta JC}$ | Junction to case (AC) | $I_T = 0.8\text{A}_{(RMS)}^1$ | TO-92   | 75   | $^\circ\text{C/W}$ |
|                 |                       |                               | SOT-223 | 30   | $^\circ\text{C/W}$ |
|                 |                       |                               | SOT-89  | 50   | $^\circ\text{C/W}$ |
| $R_{\theta JA}$ | Junction to ambient   | $I_T = 0.8\text{A}_{(RMS)}^1$ | TO-92   | 150  | $^\circ\text{C/W}$ |
|                 |                       |                               | SOT-223 | 60   | $^\circ\text{C/W}$ |
|                 |                       |                               | SOT-89  | 90   | $^\circ\text{C/W}$ |

1 - 60Hz AC resistive load condition, 100% conduction.

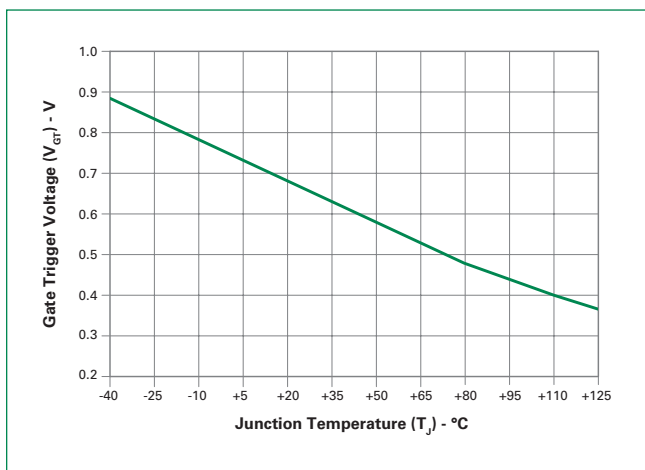
**Figure 1: Normalized DC Gate Trigger Current For All Quadrants vs. Junction Temperature**



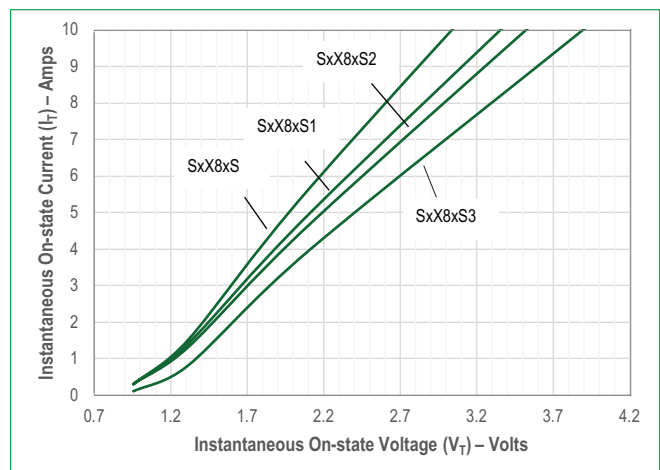
**Figure 2: Normalized DC Holding Current vs. Junction Temperature**



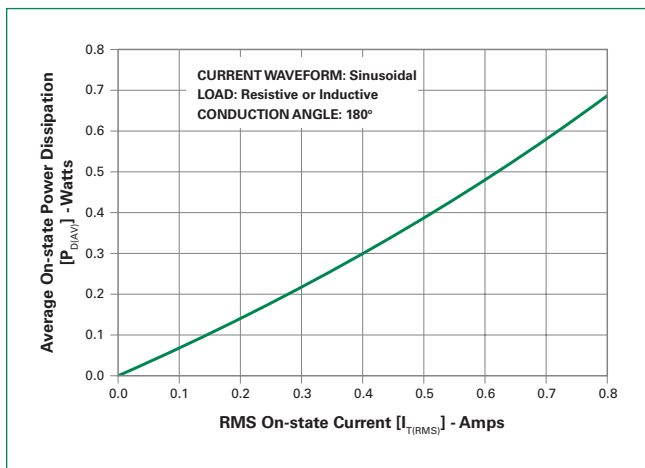
**Figure 3: Normalized DC Gate Trigger Voltage vs. Junction Temperature**



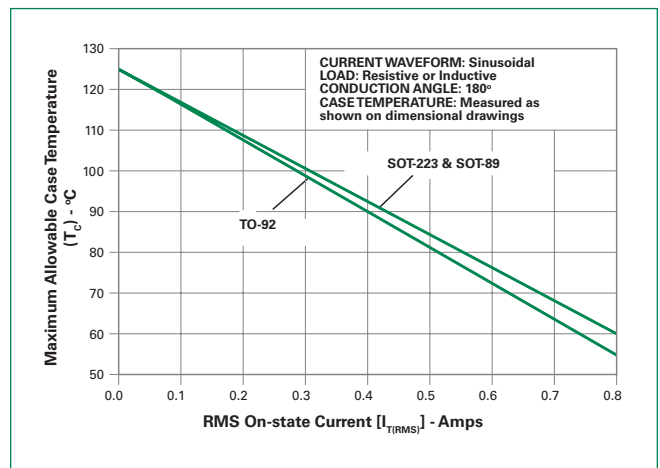
**Figure 4: On-State Current vs. On-State Voltage (Typical)**



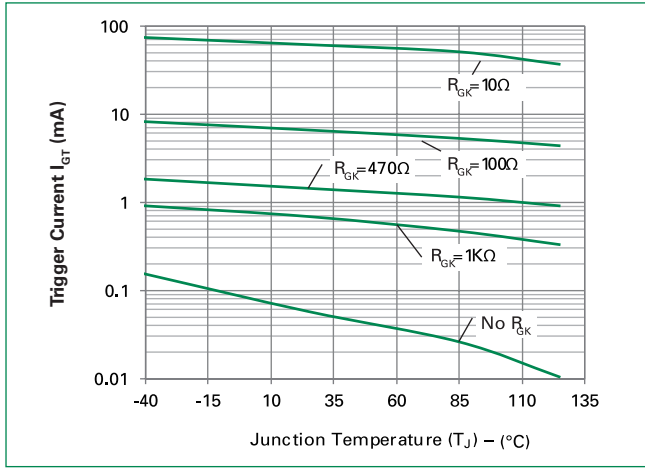
**Figure 5: Power Dissipation (Typical) vs. RMS On-State Current**



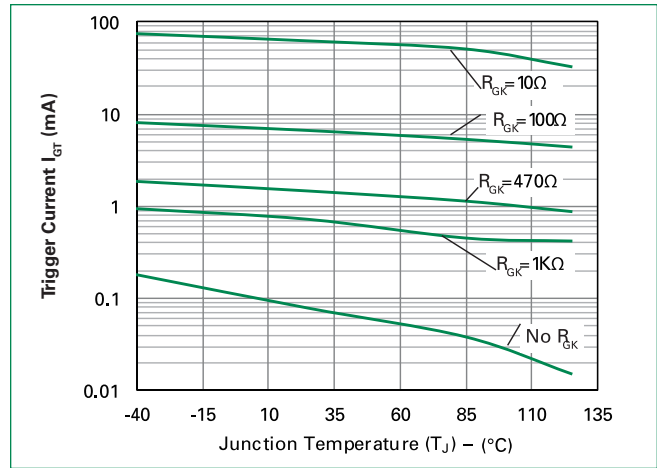
**Figure 6: Maximum Allowable Case Temperature vs. On-State Current**



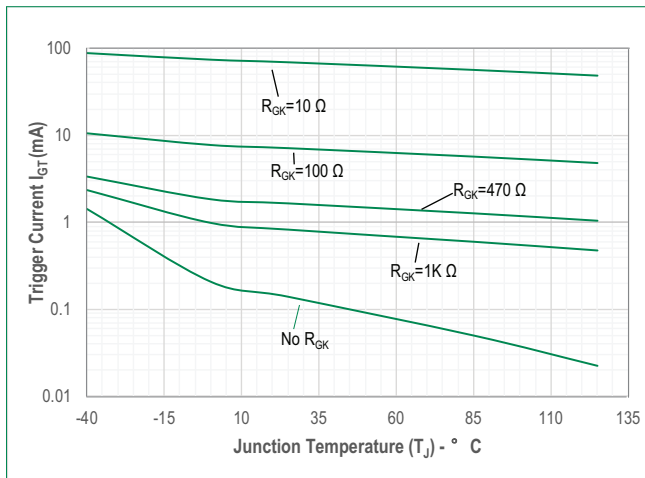
**Figure 7-1: Typical DC Gate Trigger Current with  $R_{GK}$  vs. Junction Temperature for S6X8xS**



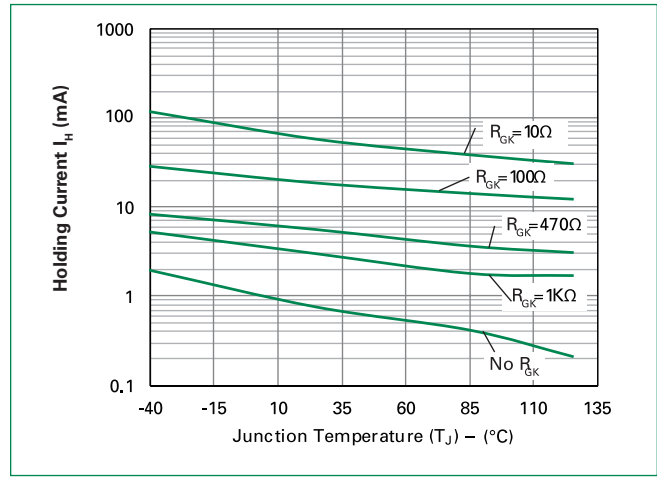
**Figure 7-2: Typical DC Gate Trigger Current with  $R_{GK}$  vs. Junction Temperature for S8X8xS**



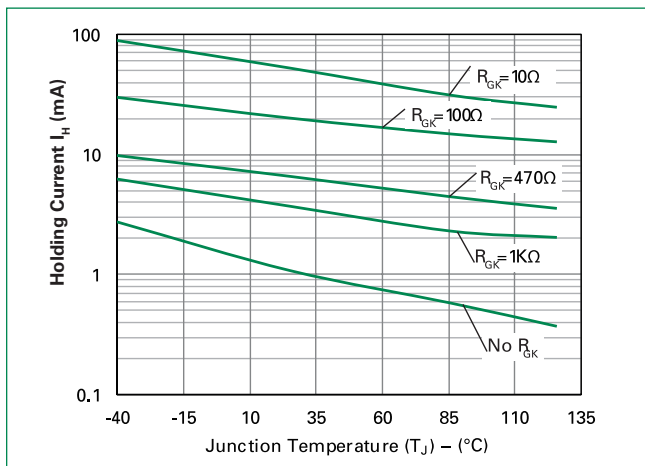
**Figure 7-3: Typical DC Gate Trigger Current with  $R_{GK}$  vs. Junction Temperature for S6X8xS3**



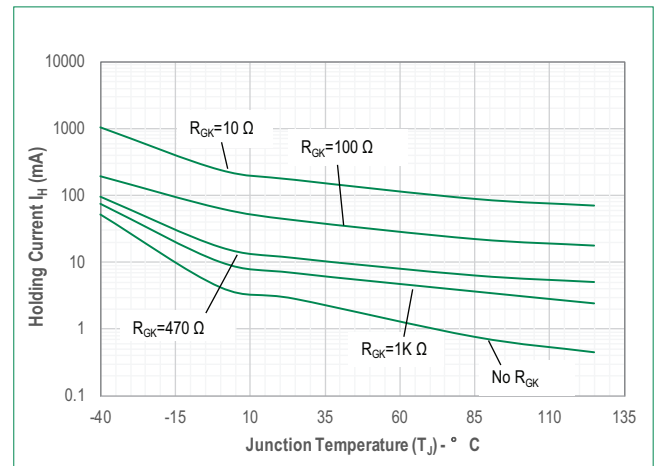
**Figure 8-1: Typical DC Holding Current with  $R_{GK}$  vs. Junction Temperature for S6X8xS**



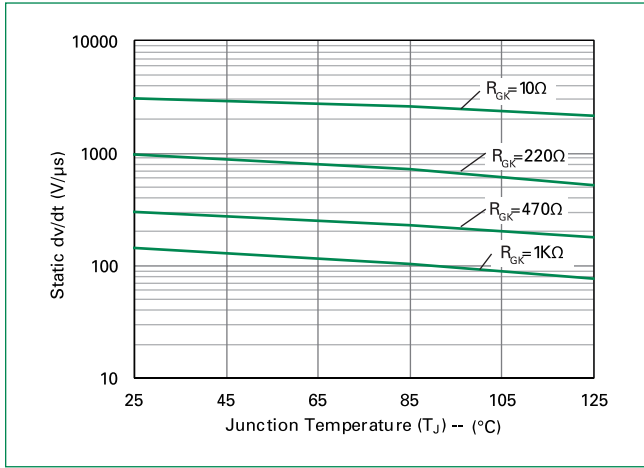
**Figure 8-2: Typical DC Holding Current with  $R_{GK}$  vs. Junction Temperature for S8X8xS**



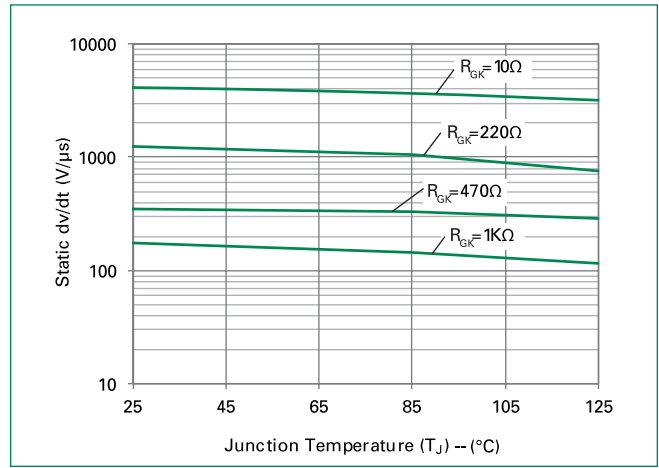
**Figure 8-3: Typical DC Holding Current with  $R_{GK}$  vs. Junction Temperature for S6X8xS3**



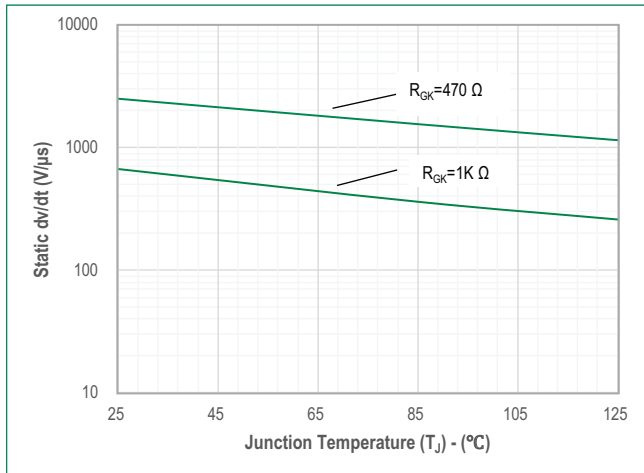
**Figure 9-1: Typical DC Static dv/dt with  $R_{GK}$  vs. Junction Temperature for S6X8xS**



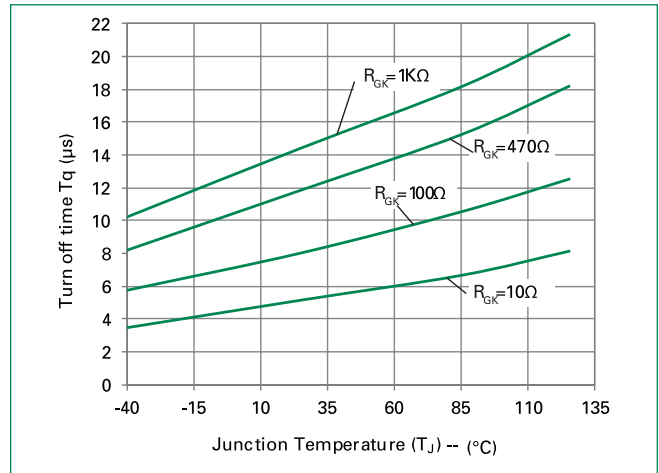
**Figure 9-2: Typical DC Static dv/dt with  $R_{GK}$  vs. Junction Temperature for S8X8xS**



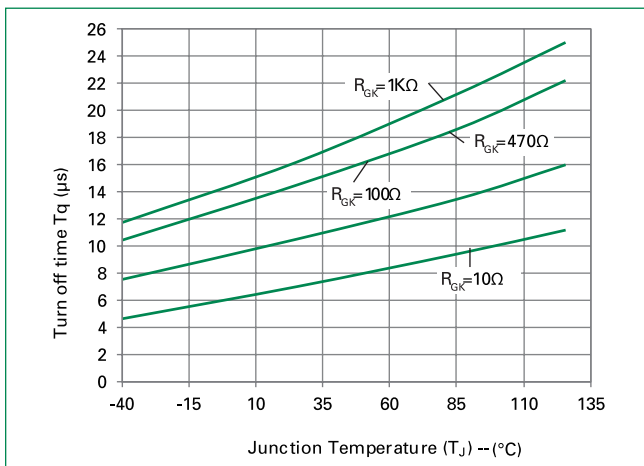
**Figure 9-3: Typical DC Static dv/dt with  $R_{GK}$  vs. Junction Temperature for S6X8xS3**



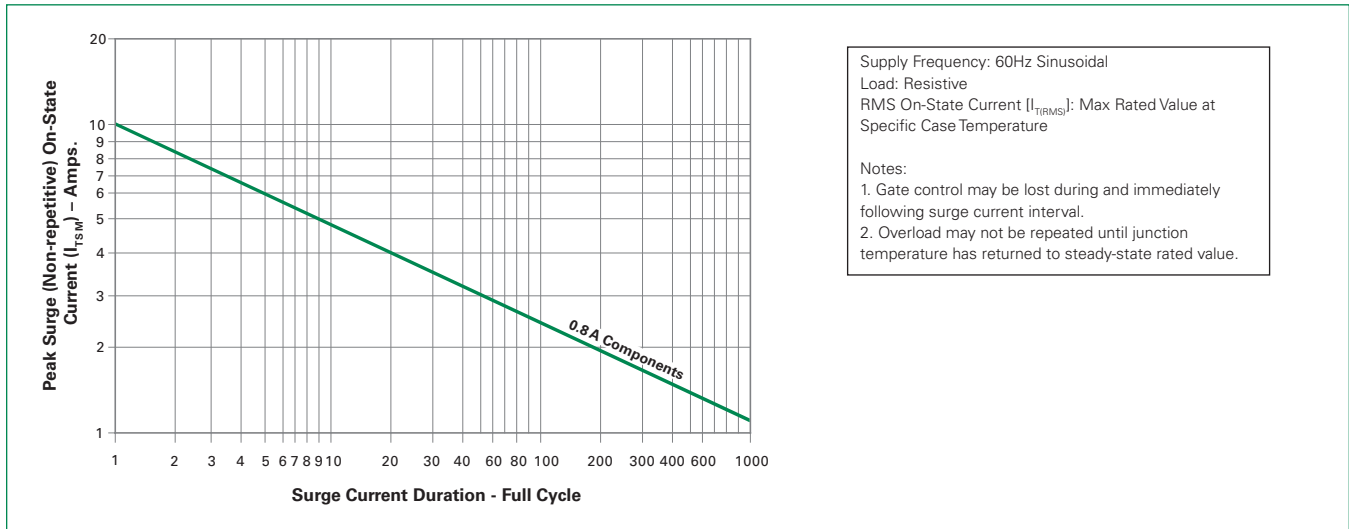
**Figure 10-1: Typical DC turn off time with  $R_{GK}$  vs. Junction Temperature for S6X8xS**



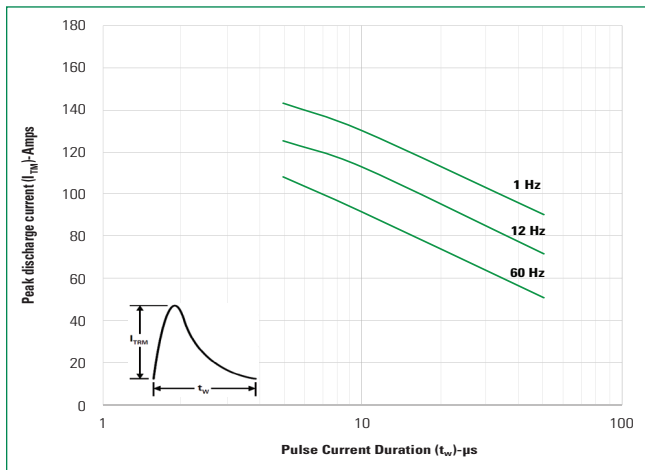
**Figure 10-2: Typical DC turn off time with  $R_{GK}$  vs. Junction Temperature for S8X8xS**



**Figure 11: Surge Peak On-State Current vs. Number of Cycles**

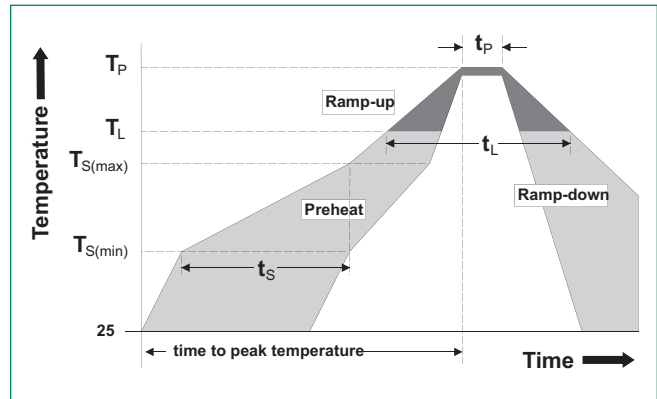


**Figure 12: Peak Repetitive Sinusoidal Pulse Current**



### Soldering Parameters

|  |                                    |                         |
|--|------------------------------------|-------------------------|
| <b>Reflow Condition</b>  |                                    | Pb – Free assembly      |
| <b>Pre Heat</b>  | - Temperature Min ( $T_{s(min)}$ ) | 150°C                   |
|  | - Temperature Max ( $T_{s(max)}$ ) | 200°C                   |
|  | - Time (min to max) ( $t_s$ )      | 60 – 180 secs           |
| <b>Average ramp up rate (Liquidus Temp) (<math>T_L</math>) to peak</b> |                                    | 5°C/second max          |
| <b><math>T_{s(max)}</math> to <math>T_L</math> - Ramp-up Rate</b>      |                                    | 5°C/second max          |
| <b>Reflow</b>  | - Temperature ( $T_L$ ) (Liquidus) | 217°C                   |
|  | - Time (min to max) ( $t_s$ )      | 60 – 150 seconds        |
| <b>Peak Temperature (<math>T_p</math>)</b>                             |                                    | 260 <sup>+0/-5</sup> °C |
| <b>Time within 5°C of actual peak Temperature (<math>t_p</math>)</b>   |                                    | 20 – 40 seconds         |
| <b>Ramp-down Rate</b>  |                                    | 5°C/second max          |
| <b>Time 25°C to peak Temperature (<math>T_p</math>)</b>                |                                    | 8 minutes Max.          |
| <b>Do not exceed</b>   |                                    | 280°C                   |



### Physical Specifications

|                        |  |
|------------------------|--|
| <b>Terminal Finish</b> | 100% Matte Tin-plated.                                 |
| <b>Body Material</b>   | UL Recognized compound meeting flammability rating V-0 |
| <b>Lead Material</b>   | Copper Alloy   |

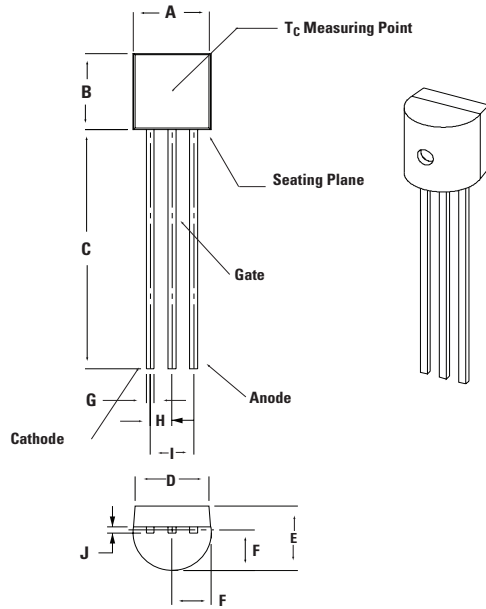
### Reliability/Environmental Tests

| Test                             | Specifications and Conditions  |
|----------------------------------|--|
| <b>AC Blocking</b>               | MIL-STD-750, M-1040, Cond A Applied Peak AC voltage @ 110°C for 1008 hours |
| <b>Temperature Cycling</b>       | MIL-STD-750, M-1051, 100 cycles; -40°C to +150°C; 15-min dwell-time        |
| <b>Temperature/Humidity</b>      | EIA / JEDEC, JESD22-A101 1008 hours; 320V - DC; 85°C; 85% rel humidity     |
| <b>High Temp Storage</b>         | MIL-STD-750, M-1031, 1008 hours; 150°C                                     |
| <b>Low-Temp Storage</b>          | 1008 hours; -40°C  |
| <b>Resistance to Solder Heat</b> | MIL-STD-750 Method 2031  |
| <b>Solderability</b>             | ANSI/J-STD-002, category 3, Test A   |
| <b>Lead Bend</b>                 | MIL-STD-750, M-2036 Cond E   |

### Design Considerations

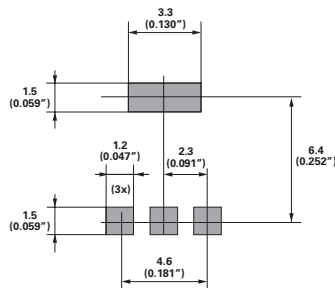
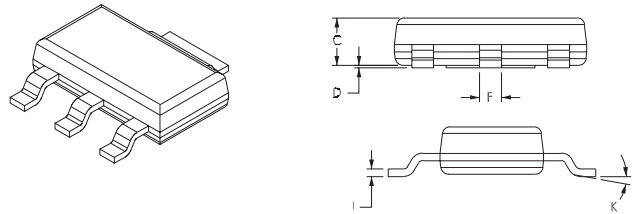
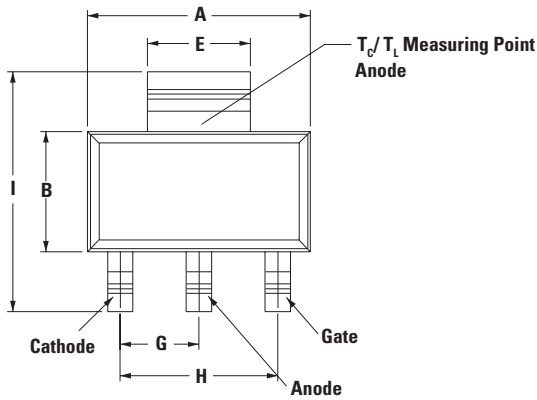
Careful selection of the correct component for the application's operating parameters and environment will go a long way toward extending the operating life of the Thyristor. Good design practice should limit the maximum continuous current through the main terminals to 75% of the component rating. Other ways to ensure long life for a power discrete semiconductor are proper heat sinking and selection of voltage ratings for worst case conditions. Overheating, overvoltage (including dv/dt), and surge currents are the main killers of semiconductors. Correct mounting, soldering, and forming of the leads also help protect against component damage.

### Dimensions – TO-92



| Dimension | Inches |       | Millimeters |       |
|-----------|--------|-------|-------------|-------|
|           | Min    | Max   | Min         | Max   |
| A         | 0.175  | 0.205 | 4.450       | 5.200 |
| B         | 0.170  | 0.210 | 4.320       | 5.330 |
| C         | 0.500  | -     | 12.70       | -     |
| D         | 0.135  | -     | 3.430       | -     |
| E         | 0.125  | 0.165 | 3.180       | 4.190 |
| F         | 0.080  | 0.105 | 2.040       | 2.660 |
| G         | 0.016  | 0.021 | 0.407       | 0.533 |
| H         | 0.045  | 0.055 | 1.150       | 1.390 |
| I         | 0.095  | 0.105 | 2.420       | 2.660 |
| J         | 0.015  | 0.020 | 0.380       | 0.500 |

### Dimensions – SOT-223

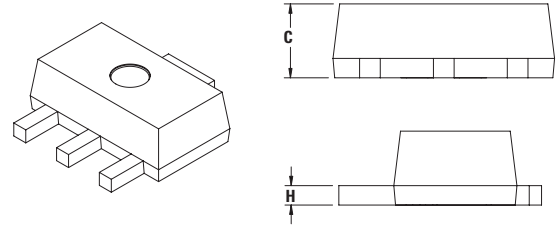
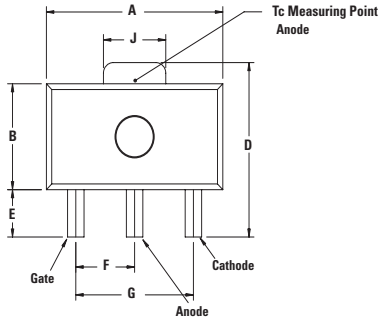


Dimensions in Millimeters (Inches)

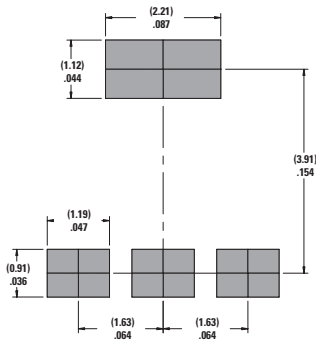
| Dimensions | Inches  |       |       | Millimeters |      |      |
|------------|---------|-------|-------|-------------|------|------|
|            | Min     | Typ   | Max   | Min         | Typ  | Max  |
| A          | 0.248   | 0.256 | 0.264 | 6.30        | 6.50 | 6.71 |
| B          | 0.130   | 0.138 | 0.146 | 3.30        | 3.50 | 3.70 |
| C          | —       | —     | 0.071 | —           | —    | 1.80 |
| D          | 0.001   | —     | 0.005 | 0.02        | —    | 0.13 |
| E          | 0.114   | 0.118 | 0.124 | 2.90        | 3.00 | 3.15 |
| F          | 0.024   | 0.027 | 0.034 | 0.60        | 0.70 | 0.85 |
| G          | —       | 0.090 | —     | —           | 2.30 | —    |
| H          | —       | 0.181 | —     | —           | 4.60 | —    |
| I          | 0.264   | 0.276 | 0.287 | 6.70        | 7.00 | 7.30 |
| J          | 0.009   | 0.010 | 0.014 | 0.23        | 0.26 | 0.35 |
| K          | 10° MAX |       |       |             |      |      |



### Dimensions – SOT-89



Pad Layout for SOT-89



Dimensions in Millimeters (Inches)

| Dimension | Inches |       |       | Millimeters |      |      |
|-----------|--------|-------|-------|-------------|------|------|
|           | Min    | Typ   | Max   | Min         | Typ  | Max  |
| A         | 0.173  | —     | 0.181 | 4.40        | —    | 4.60 |
| B         | 0.090  | —     | 0.102 | 2.29        | —    | 2.60 |
| C         | 0.055  | —     | 0.063 | 1.40        | —    | 1.60 |
| D         | 0.155  | —     | 0.167 | 3.94        | —    | 4.25 |
| E         | 0.035  | —     | 0.047 | 0.89        | —    | 1.20 |
| F         | 0.056  | —     | 0.062 | 1.42        | —    | 1.57 |
| G         | 0.115  | —     | 0.121 | 2.92        | —    | 3.07 |
| H         | 0.014  | —     | 0.017 | 0.35        | —    | 0.44 |
| I         | 0.014  | —     | 0.019 | 0.36        | —    | 0.48 |
| J         | 0.064  | 0.067 | 0.072 | 1.62        | 1.69 | 1.83 |

### Product Selector

| Part Numbr | Voltage |      |      | Gate Sensitivity | Package |
|------------|---------|------|------|------------------|---------|
|            | 400V    | 600V | 800V |                  |         |
| SxX8BS     | X       | X    | -    | 200 $\mu$ A      | SOT-89  |
| SxX8ES     | X       | X    | X    | 200 $\mu$ A      | TO-92   |
| SxX8TS     | X       | X    | X    | 200 $\mu$ A      | SOT-223 |
| SxX8BS1    | X       | X    | -    | 5 $\mu$ A        | SOT-89  |
| SxX8ES1    | X       | X    | X    | 5 $\mu$ A        | TO-92   |
| SxX8TS1    | X       | X    | X    | 5 $\mu$ A        | SOT-223 |
| SxX8BS2    | X       | X    | -    | 50 $\mu$ A       | SOT-89  |
| SxX8ES2    | X       | X    | X    | 50 $\mu$ A       | TO-92   |
| SxX8TS2    | X       | X    | X    | 50 $\mu$ A       | SOT-223 |
| SxX8TS3    | -       | X    | -    | 450 $\mu$ A      | SOT-223 |

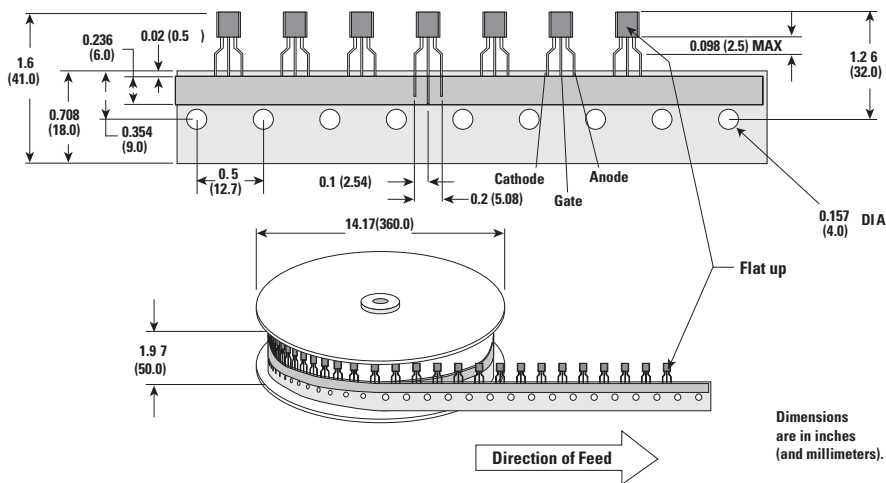
### Packing Options

| Part Number | Marking | Weight | Packing Mode | Base Quantity |
|-------------|---------|--------|--------------|---------------|
| SxX8ESy     | SxX8ESy | 0.217g | Bulk         | 2500          |
| SxX8ESyAP   | SxX8ESy | 0.217g | Ammo Pack    | 2000          |
| SxX8ESyRP   | SxX8ESy | 0.217g | Tape & Reel  | 2000          |
| SxX8TSyRP   | SxX8TSy | 0.120g | Tape & Reel  | 1000          |
| SxX8BSyRP   | xX8y    | 0.053g | Tape & Reel  | 1000          |
| SxX8BSyRP1  | xX8y    | 0.053g | Tape & Reel  | 1000          |

Note: x = voltage/100, y = gate sensitivity

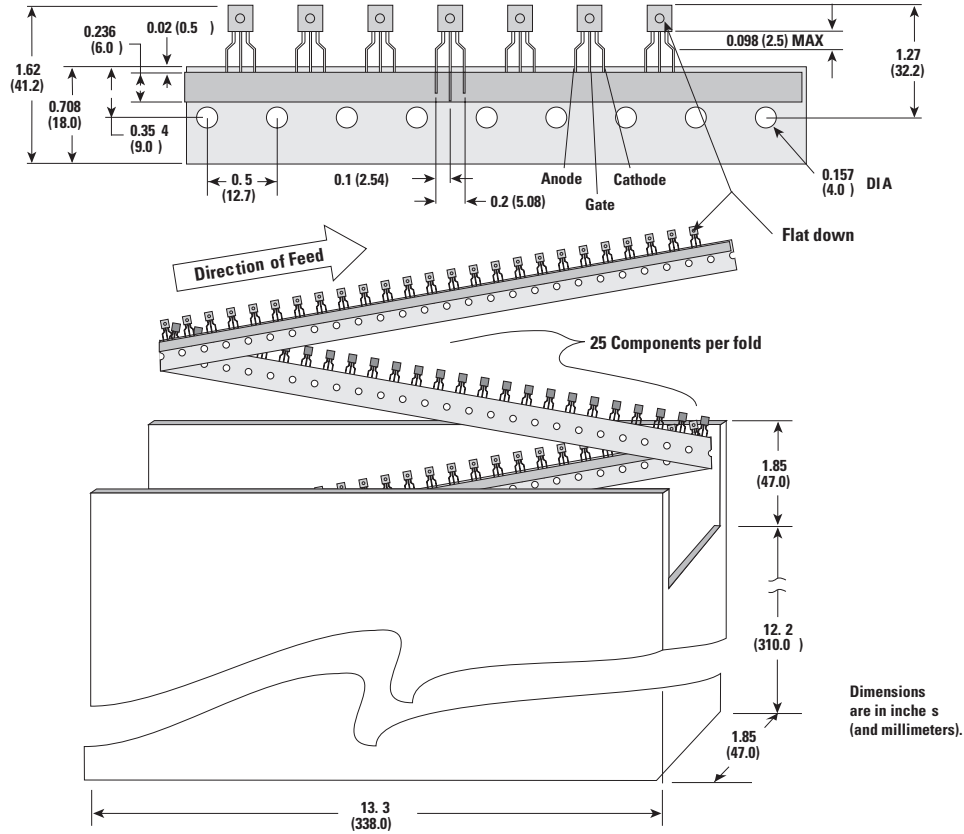
### TO-92 (3-lead) Reel Pack (RP) Radial Leaded Specifications

Meets all EIA-468-C Standards

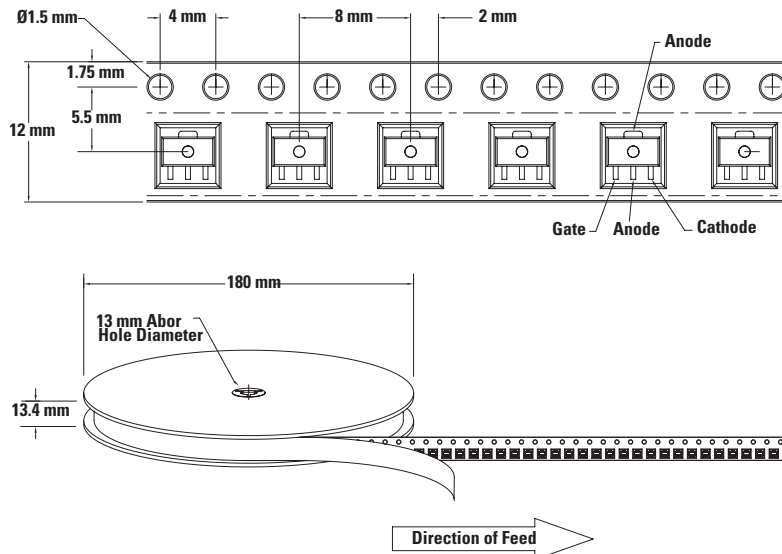


### TO-92 (3-lead) Ammo Pack (AP) Radial Leaded Specifications

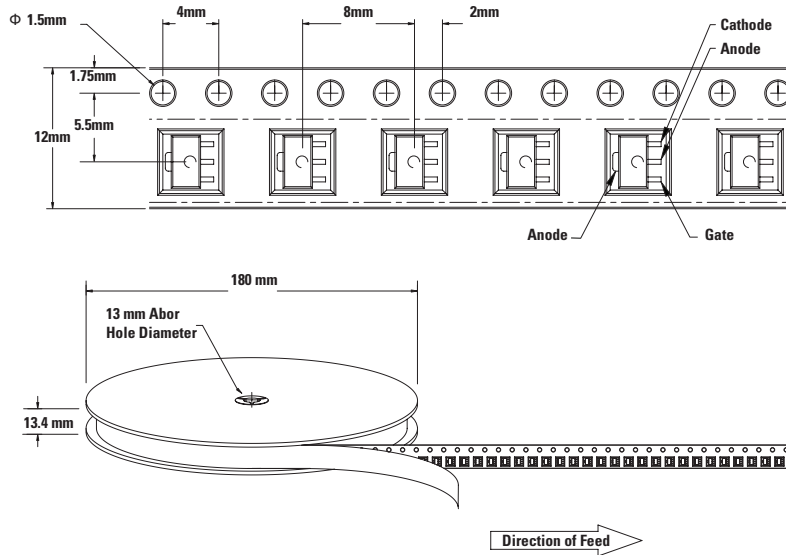
Meets all EIA-468-C Standards



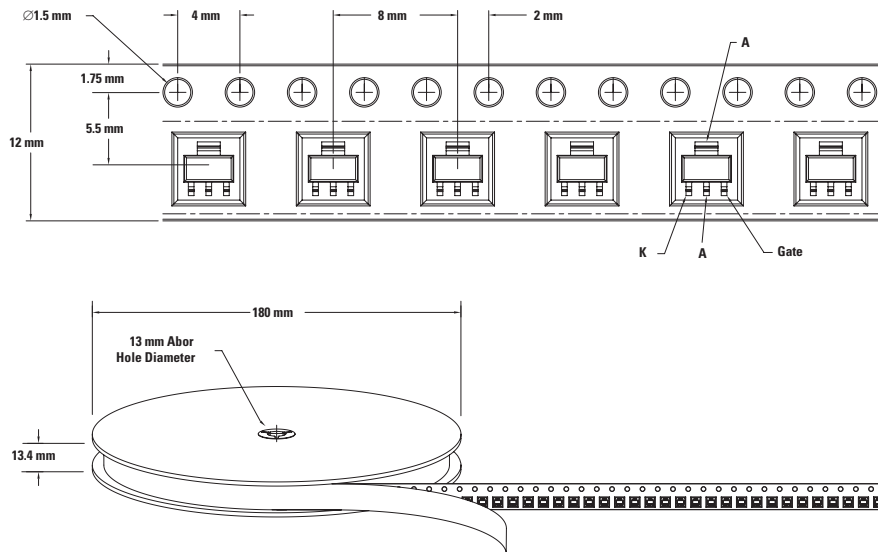
### SOT-89 Reel Pack (RP) Specifications



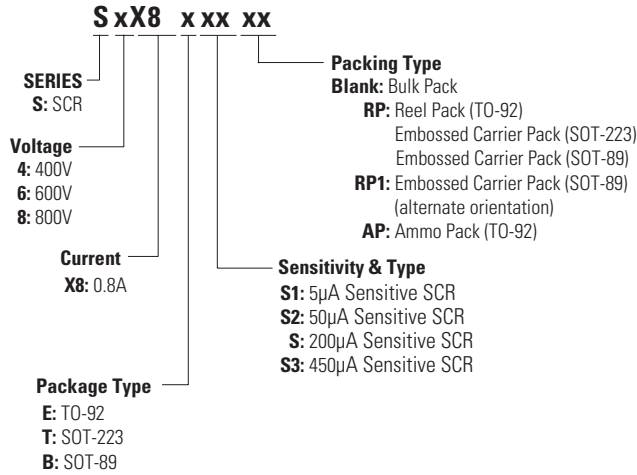
### SOT-89 Reel Pack (RP1) Specifications



### SOT-223 Reel Pack (RP) Specifications



### Part Numbering System



### Part Marking System

